



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

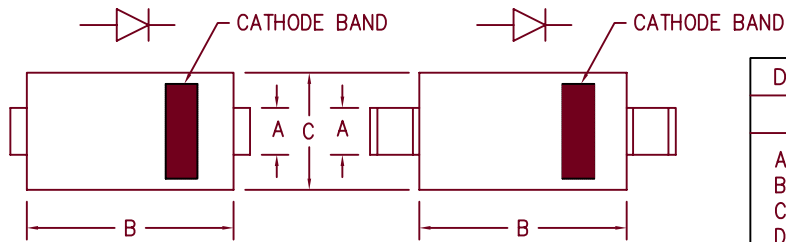
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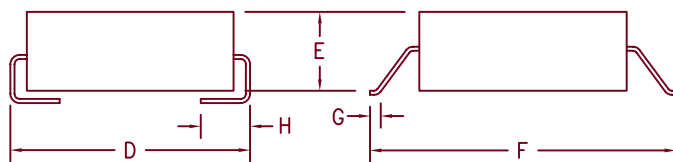
3 Amp Schottky Rectifier 5820SM — 5822SM



D0214AB

D0215AB

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.117	.123	2.97	3.12	
B	.260	.280	6.60	7.11	
C	.220	.245	5.59	6.22	
D	.307	.322	7.80	8.18	
E	.075	.095	1.91	2.41	
F	.380	.400	9.65	10.16	
G	.025	.040	.640	1.02	
H	.030	.060	.760	1.52	



Microsemi Catalog Number	Industry Part No.	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
5820SM*	MBR320T3 SK32	20V	20V
5821SM*	MBR330T3 SK33	30V	30V
5822SM*	MBR340T3 SK34	40V	40V

*Add Suffix J For J Lead or G For Gull Wing Lead Configuration

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low Forward Voltage
- High Reliability
- High Current Capability
- Surface mount package

Electrical Characteristics					
		5820SM	5821SM	5822SM	
Average forward current	$I_F(AV)$	3A	3A	3A	Square wave, $T_L = 127^\circ C$, $R_{\theta JL} = 20^\circ C/W$ 8.3ms, half sine, $T_J = 150^\circ C$ $I_{FM} = 1A, T_J = 25^\circ C^*$ $I_{FM} = 3A, T_J = 25^\circ C^*$ $I_{FM} = 9.4A, T_J = 25^\circ C^*$ $V_{RRM}, T_J = 25^\circ C$ $V_R = 5.0V, T_J = 25^\circ C$
Maximum surge current	I_{FSM}	150A	150A	150A	
Max peak forward voltage	V_{FM}	.36V	.37V	.38V	
Max peak forward voltage	V_{FM}	.46V	.48V	.50V	
Max peak forward voltage	V_{FM}	.65V	.67V	.70V	
Max peak reverse current	I_{RM}	1.5mA	1.5mA	1.5mA	
Typical junction capacitance	C_J	265pF	265pF	265pF	

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Mechanical Characteristics		
Storage temperature range	T_{STG}	-55°C to 150°C
Operating junction temp range	T_J	-55°C to 150°C
Maximum thermal resistance	$R_{\theta JL}$	20°C/W Junction to Lead
Weight		.008 ounces (.22 grams) typical



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05-09-07 Rev. 4

5820SM – 5822SM

Figure 1
Typical Forward Characteristics

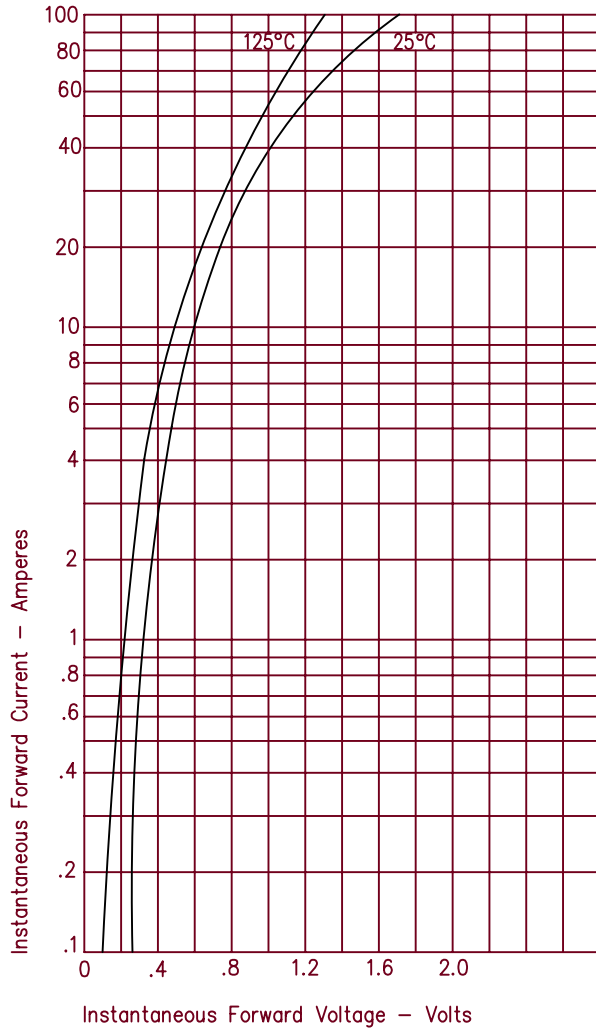


Figure 3
Typical Junction Capacitance

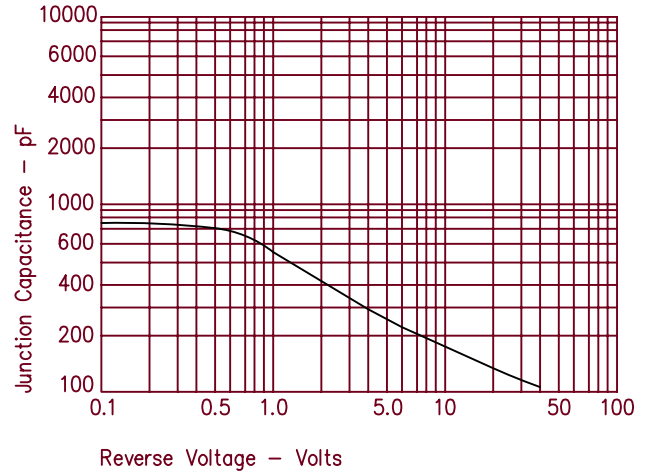


Figure 2
Typical Reverse Characteristics

